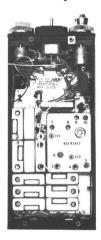


# MASTR Personal Series

PROGRESS LINE

PE MODELS
SYSTEMS BOARD AND CASE ASSEMBLY 19D417103G1
(5-FREQUENCY WITH TYPE 99 DECODER)



## **SPECIFICATIONS** \*

MODEL NUMBERS

19D417103G1

CONTROLS

138-174 MHz

Volume ON-OFF Switch
Squelch Control
Five-Frequency Selector Switch
PTT Switch
Tone Option Switch
Flexible Antenna
Accessory Jack

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

## TABLE OF CONTENTS

SPECIFICATIONS	Cover
DESCRIPTION	1
CIRCUIT ANALYSIS	
DC Switching PTT Switch	1 2
REPEATING OSCILLATOR MODULES	4
OUTLINE DIAGRAM	4
SCHEMATIC DIAGRAM	5
PARTS LIST	6
PRODUCTION CHANGES	7
MULTI-FREQUENCY MODIFICATIONS	8
ILLUSTRATIONS	
Figure 1 - Audio Switching	1 1 2

- WARNING -

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

## DESCRIPTION

System Board A701 provides system interconnections between the transmitter, receiver, tone options and operating controls in 138 MHz to 170 MHz, Five-Frequency with Type 99 Decoder PE Models. The System Board contains transmitter oscillator modules A5, A6, A10, A11 and A12, and receiver oscillator modules A13, A14 and A15. In addition to oscillator modules, the System Board contains 5.4 Volt Regulator Module A2, Compensator Module A3, Modulator Module A4, optional Compressor Module A50, System relay K1 and audio and DC switching circuitry.

Jacks J702 and J703 are connected to the system board and provide contacts for an external antenna, speaker, and microphone. J702 provides contacts for the external antenna and speaker, and J703 provides contacts for an external microphone. Placing the radio into the vehicular charger automatically connects the jack contacts to the external circuitry. The radio is also connected to the external antenna when placed in the desk charger.

## CIRCUIT ANALYSIS

### AUDIO SWITCHING

Audio switching for the Speaker/Microphone LS1 is controlled by diode CR5 as shown in Figure 1.

Pressing PTT switch S701 forward biases diode CR5, permitting audio from LS1 to be applied to transmitter audio module A1.

Keying the external microphone permits audio to be applied directly to the transmitter audio module.

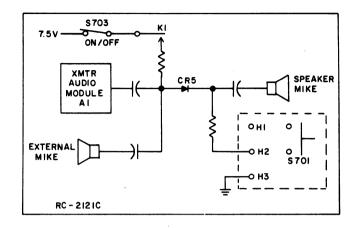


Figure 1 - Audio Switching Circuit

#### DC SWITCHING

Operation of system relay K1 is controlled by diode CR2 (see Figure 2).

Pressing S701 forward biases CR2, completing the relay path to ground. This energizes relay K1, and switches the battery voltage to the transmitter audio and regulator modules. Energizing K1 also connects the transmitter output to the antenna.

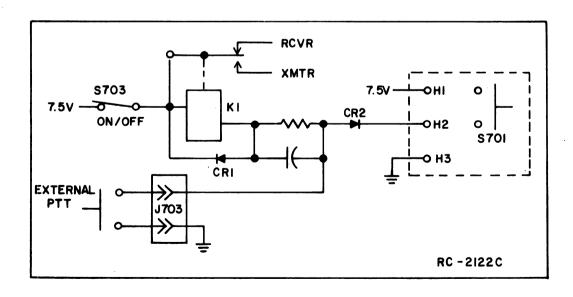


Figure 2 - DC Switching Circuit

PTT SWITCH (A705)

Solid State PTT switch S701 forward biases diode CR2 to energize relay K1 and key the radio. When S701 is pressed PNP, transistor Q1 conducts. Transistor Q1 conducting applies a positive voltage to the base of NPN transistor Q2, causing Q2 to also conduct. Transistor Q2 conducting, provides a conduction path to ground for diode CR2. Relay K1 is energized and the radio is keyed.

## REPEATING OSCILLATOR MODULES

Both the transmitter and receiver can be adapted to repeat the use of the same frequency without the use of additional Oscillator Modules. The Oscillator Module is replaced by a diode, allowing the frequency selector switch to have the same frequency on one or more switch positions even though only one Oscillator Module is used for each of the repeated channels. A typical diagram with repeated Oscillator Modules is shown in Figure 3.

Complete instructions for multi-frequency modifications are contained in the Multi-Frequency Modification Diagram (see Table of Contents).

For radios equipped with Channel Guard, Type 90 Encoders/Decoders or Type 99 Decoders, repeating Oscillator Modules also permits switching or disabling tones on the same RF frequency with the multi-frequency switch. Also, the tone and RF frequency can be changed at the same time.

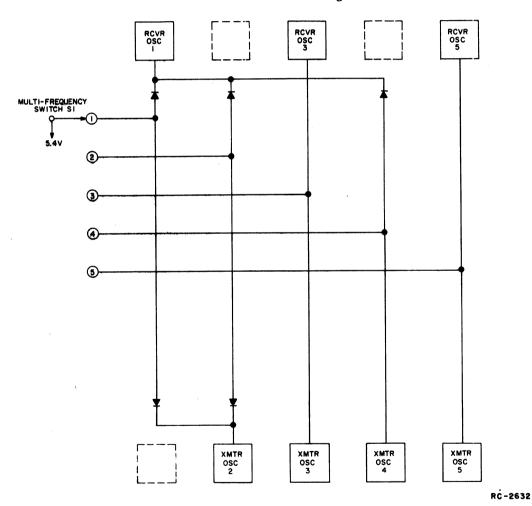
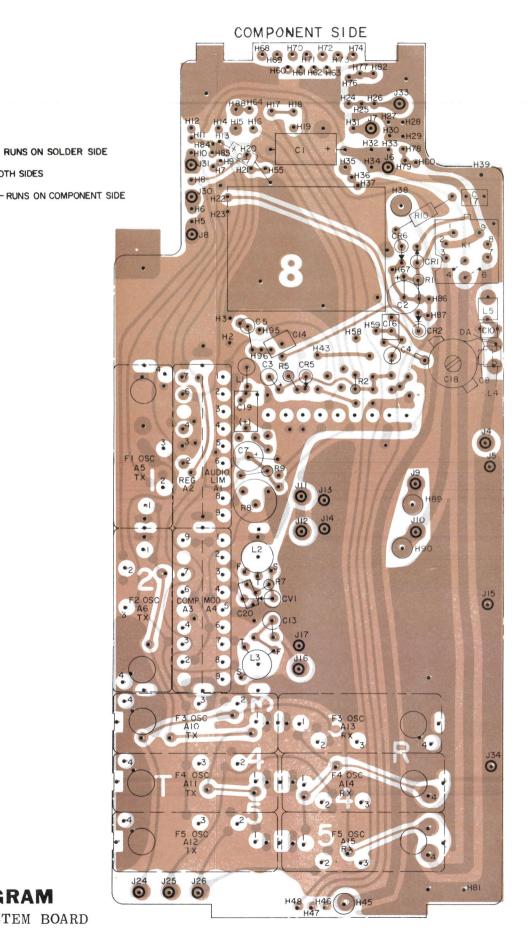


Figure 3 - Repeating Oscillator Modules

GENERAL ELECTRIC COMPANY+ MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS+LYNCHBURG, VIRGINIA 24502 U.S.A.

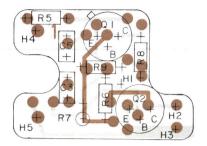


RUNS ON BOTH SIDES



# H62 H77 H73 H71 H69 H76 H76 H76 H63 H62 H61 H60 H76 SOLDER SIDE H28 H27 J7 H31 H78 H33 H32 1 J30 H22 H5. J4 J5 © G J15 )35 **O** J25 J24 .H81 @J2 J26

# A 705

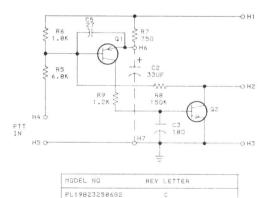


LEAD IDENTIFICATION FOR QI AND Q2



IN-LINE OR TRIANGULAR
TOP VIEW NOTE, LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION

(19B232296, Rev. 3) (19B232970, Sh. 1, Rev. 1) (19B232970, Sh. 2, Rev. 2)



NOTE: C2 IS PART OF KIT 19A136579

(19B232959, Rev. 4)

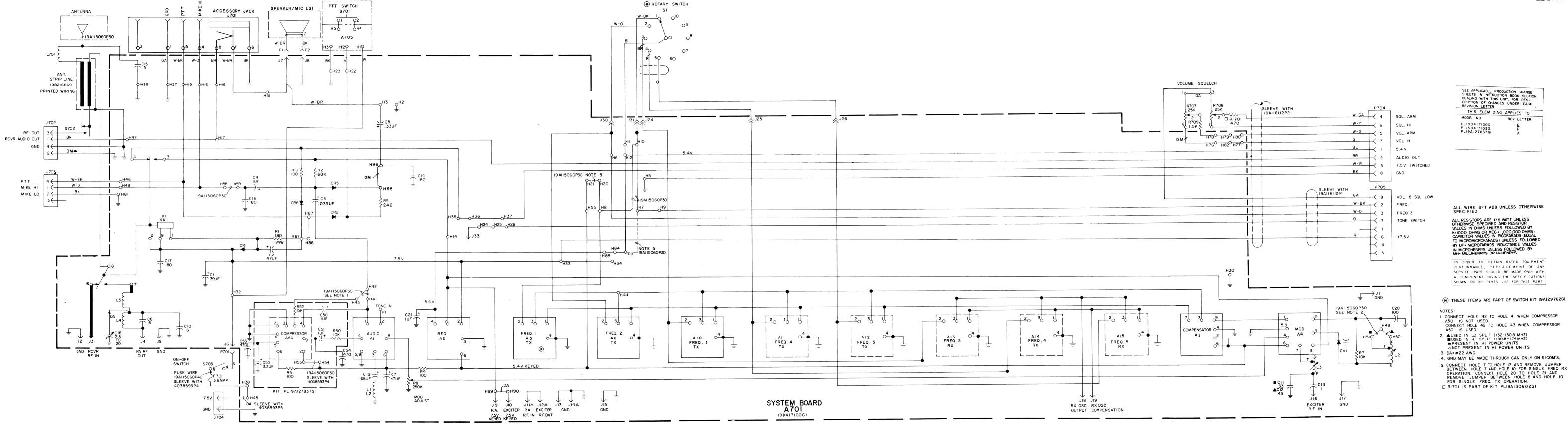
# **OUTLINE DIAGRAM**

138—174 MHZ SYSTEM BOARD

Issue 5

(19D416976, Sh. 2, Rev. 8) (19D416976, Sh. 3, Rev. 8)

(19D416976, Sh. 2, Rev. 8)



SEE APPLICABLE PRODUCTION CHANGE SHEETS IN INSTRUCTION BOOK SECTION DEALING WITH THIS UNIT, FOR DESCRIPTION OF CHANGES UNDER EACH REVISION LETTER. THIS ELEM DIAG APPLIES TO

MODEL NO REV LETTER MODEL NO PL19D417100G1 PL19D417103G1 PL19**A**127**837**G1

ALL WIRE SFT #28 UNLESS OTHERWISE SPECIFIED

ALL RESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K: 1000 OHMS OHMS ON MEG = 1,000,000 OHMS CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF = MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H=HENRYS.

IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY
SERVICE PART SHOULD BE MADE ONLY WITH
A COMPONENT HAVING THE SPECIFICATIONS
SHOWN ON THE PARTS LIST FOR THAT PART

NOTES:

1. CONNECT HOLE 42 TO HOLE 41 WHEN COMPRESSOR A50 IS NOT USED.

CONNECT HOLE 42 TO HOLE 43 WHEN COMPRESSOR A50 IS USED.

2. AUSED IN LO SPLIT (132-150.8 MHZ)

USED IN HI SPLIT (150.8-174MHZ)

PRESENT IN HI POWER UNITS

ANOT PRESENT IN HI POWER UNITS

4. GND MAY BE MADE THROUGH CAN ONLY ON SICOM'S.

5. CONNECT HOLE 7 TO HOLE 13 AND REMOVE JUMPER BETWEEN HOLE 7 AND HOLE 10 FOR SINGLE FREQ. RX OPERATION. CONNECT HOLE 20 TO HOLE 21 AND REMOVE JUMPER BETWEEN HOLE 8 AND HOLE 10 FOR SINGLE FREQ. TX OPERATION.

| RI701 IS PART OF KIT PLI9A130602G1

# **SCHEMATIC DIAGRAM**

138—174 MHZ SYSTEM BOARD

PARTS LIST LB14701D SYSTEM BOARD/CASE ASSEMBLY 19D417103G1 AND ASSOCIATED ASSEMBLIES SYMBOL | GE PART NO.

19A115250P1

CR1

	51.	19D417103G1	CR1	19A115250P1
		AND ASSOCIATED ASSEMBLIES	CR2	5494922P1
			CR5	5494922P1
			CR6	19A115250P1
SYMBOL	GE PART NO.	DESCRIPTION	CV1	5495769P9
A701		SYSTEM BOARD 19D417100G1	Jl* thru	19A116366P4
A1	19C320062G1	Transmitter Audio Module.	J5*	19A116366P1
			J6	19A116366P2
A2*	19C328070G1	Regulator Module.	thru J8	
	10001100500	In REV D & earlier:	J9*	19A116366P4
	19C311905G2	Regulator Module.	and J10*	
A3	19C320060G1	Oscillator Compensator Module.		19A116366Pl
A4	19C320084G1	Modulator Module.	J15* thru J21*	19A116366P4
			-	19A116366P1
C1	5491674P30	Tantalum: 39 $\mu f$ $\pm 20 \mbox{\ensuremath{^{\circ}}}_c$ , 10 VDCW; sim to Sprague Type 162D.	J24* thru	19A116366P4
C2	5491674P42	Tantalum: 47 $\mu f$ $\pm 20\%$ , 6 VDCW; sim to Sprague Type 162D.	J26*	10417.2222
C3*	5491674P51	Tantalum: 0.033 µf ±10%, 35 VDCW; sim to	J30*	19A116366P1 19A116366P4
		Kemet T376P33K03AS.	and J31*	1
	5491674P49	In REV C: Tantalum: $0.068 \ \mu f \ \pm 10\%$ , 20 VDCW; sim to Sprague Type 162D.		19A116366P1
			J32*	19A116366P2
	1	In REV B and earlier:		
	5491674P1	Tantalum: 1.0 $\mu f$ +40-20, , 10 VDCw; sim to Sprague Type 162D.	J33 and J34	19A116366P2
C4	5491674P1	Tantalum: 1.0 $\mu f$ +40-20%, 10 VDCW; sim to Sprague Type 162D.		
C5*	5491674P52	Tantalum: 0.33 $\mu f$ ±10%, 20 VDCW; sim to Kemet T376B334K020AS.	K1*	19B209562P2
		In REV C:		
	5491674P48	Tantalum: $0.68~\mu f~\pm 10 \%$ , 10 VDCW; sim to Sprague Type $162D$ .		19B209562P1
		In REV B and earlier:		
	19A116244P2	Ceramic: 0.022 μf ±20, 50 VDCW.		
C7	5491674P42	Tantalum: 47 $\mu$ f $\pm 20$ °c, 6 VDCW; sim to Sprague Type 162D.	L1	19B209420P1
С8	19A116114P20	Ceramic: 6 pf ±5%, 100 VDCW; temp coef 0 PPM.	L2	19A127798G1
C10	19A116114P20	Ceramic: 6 pf ±5%, 100 VDCW; temp coef 0 PPM.		19B209436P1
C13	5491601P120	Phenolic: 1.0 pf ±5%, 500 VDCW.	L3	19B216910G1
C14	19A116114P10073	Ceramic: 180 pf $\pm 10^{\circ}$ , 100 VDCW; temp coef -3300 PPM.		19B209436P1
C15	5496218P36	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	LA and L5	19B216320P3
C16 and C17	19A116114P10073	Ceramic: 180 pf $\pm 10\%$ , 100 VDCW; temp coef $-3300$ PPM.	R1*	3R151P181J
C18	19B209351P2	Variable: 2.5 to 20 pf, 200 VDCW; sim to Matshushita ECV-1/2-W2OP32.	K1*	JRIGIPIOIS
C19	19C307102P19	Tantalum: 68 ±20%, 4 VDCW.		3R151P221J
C20	19A116114P8065	Ceramic: 100 pf ±5%, 100 VDCW; temp coef -1500 PPM.		001515001
C21*	5491674P1		ne :	3R151P391J
C21*	24910/441	Tantalum: 1.0 $\mu f$ +40-207, 10 VDCW; sim to Sprague Type 162D. Added by REV E.	R2*	3R151P683J
				3R151P913J
		}		
			·	

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
				<b></b>		
DIODES AND RECTIFIERS	R5*	3R151P241J	Composition: 240 ohms ±5%, 1/8 w.			JACKS AND RECEPTACLES
Silicon, fast recovery, 225 mA, 50 PIV.			In REV B and earlier:	J701	19B216594G2	Connector, female: 6 contacts.
Silicon; sim to Type 1N456.		3R151P103J	Composition: 10K ohms ±5%, 1/8 w.	J702		See Mechanical Parts RC2605 items 14, 16.
Silicon; sim to Type 1N456.	R6*	3R151P222J	Composition: 2.2K ohms ±5%, 1/8 w. Deleted by REV C.	J703		See Mechanical Parts RC2605 items 14, 48.
Silicon, fast recovery, 225 mA, 50 PIV.	R7	3R151P103J	Composition: 10K ohms ±5%, 1/8 w.	J704		See Mechanical Parts RC2605 items 51-53.
Silicon, capacitive.	R8	19A116412P4	Variable, cermet: 250K ohms ±10%, 1/2 w;	į.		RELAYS
JACKS AND RECEPTACLES		10111011211	sim to Helipot Model 62 PF.	K1*	19A127836G1	Sensitive: 95 ohms ±10%, 2 form C contacts, 5.5 to
Contact, electrical: sim to Concord 10-891-1.	R9 and	3R151P101K	Composition: 100 ohms $\pm 10\%$ , 1/8 w.	1		9.0 VDC (over the temp range indicated); sim to C.P. Clare MF1401G01. Deleted by REV B.
Earlier than REV A:	R10				l	
Contact, electrical: sim to Cambion 3232-1.	ì		SOCKETS			
	XK1*	19A115834P5	Contact, electrical: sim to AMP 4-331272-3. (Quantity 7). Deleted by REV A.	L701	19A127815P1	Coil.
Contact, electrical: sim to Cambion 3233-1.			(Qualitity /), Defeted by REV N.			
	A705*		PUSH TO TALK SWITCH BOARD	P701	19A115834P4	Contact, electrical: sim to AMP 2-332070-9.
Contact, electrical: sim to Concord 10-891-1.		1	19B232586G1 (Added by REV E)	P704	19A127569G1	Plug: 8 contacts.
Earlier than REV A:			(Deleted by REV F)	and P705	12210000	
Contact, electrical: sim to Cambion 3232-1.	1			P706*	19A127569G1	Plug: 8 contacts. Deleted by REV B.
Contact, electrical: sim to Concord 10-891-1.	Cl	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef	1,00,	20012130001	. ang. o contactor boasted by Abr b.
Earlier than REV A:			-3300 РРМ.			RESISTORS
Contact, electrical: sim to Cambion 3232-1.	C3	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.	R707	19A116227P1	Resistor/Switch: variable, carbon film, 25K ohms
Contact, electrical: sim to Concord 10-891-1.	C4*	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300	ĺ		$\pm 20\pi$ , 1/8 w, (Includes S703), SPST, 3 amp at 125 VAC.
Earlier than REV A:			PPM. Added by REV A.	R708	19A116227P2	Variable, carbon film: 25K ohms $\pm 20\%$ , 1/8 w.
Contact, electrical: sim to Cambion 3232-1.			TRANSISTORS	R709	3R151P152K	Composition: 1.5K ohms $\pm 10\%$ , 1/8 w.
Contact, electrical: sim to Concord 10-891-1.	QI	19A129187P1	Silicon, PNP.	R710*	3R151P103K	Composition: 10K ohms $\pm 10\%$ , 1/8 w. Deleted by
Earlier than REV A:	Q2	19A116201P3	Silicon, NPN.			REV B.
Contact, electrical: sim to Cambion 3232-1.	"					
		į.	RESISTORS	8701		See Mechanical Parts RC2605, items 33-39.
	R1	3R151P103J	Composition: 10K ohms ±5%, 1/8 w.			
Contact, electrical: sim to Cambion 3233-1.			2 24 25 45 148 5	S702		See Mechanical Parts RC2605, items 40-47.
Deleted by REV A.	R2	3R151P332J	Composition: 3.3K ohms ±5%, 1/8 w.	S703		(Part of R707).
Contact, electrical: sim to Cambion 3233-1.	R3	3R151P154J	Composition: 150K ohms ±5%, 1/8 w.	S704*	19A116648P5	Toggle: SPDT, sim to C & K Component 7107SDG.
	R4	3R151P182J	Composition: 1.8K ohms ±5%, 1/8 w.	3704*	19/11/004/01/3	Deleted by REV B.
RELAYS	A705*	1	PUSH TO TALK SWITCH BOARD			
Relay, hermetic sealed: (between 45 to 100 ohms), ±107, 2 form C contacts, 5.0 VDC nominal, 1.0 w max operating; sim to GE 3SCS1002A2.			19B232586G2 (Added by REV F)			ASSOCIATED ASSEMBLIES
In REV A:	1					SYSTEM BOARD (The following components are physically located
Relay, hermetic sealed: 98 ohms ±10c, 2 form C contacts, 6.0 VDC nominal, 1.0 w max operating; sim to GE 3SCS1001A2.	C1*	19Al16114P10073	Ceramic: 180 pf ±107, 100 VDCW; temp coef -3300 PPM. Deleted by REV A.			on A701 when used, but are not present on board i A701 is ordered separately).
	С3	19A116114P10073	Ceramic: 180 pf $\pm 10\%$ , 100 VDCW; temp coef $-3300$ PPM.			NOTE: When reordering A5, A6, A10-A12 give GE Part Number and exact crystal frequency.
INDUCTORS	C5*	19A116114P2044	Ceramic: 27 pf $\pm 5\%$ , 100 VDCW; temp coef -80 PPM. Added by REV B.			Crystal Freq = Operating Freq 12
sim to Jeffers 4436-1K.			Added by REV B.			
Coil: 6.05-6.9 µh. Includes:				A5 and	4EG27A10	Transmitter Oscillator.
Tuning slug.	Q1	19A129187P1	Silicon, PNP.	A6		
Coil. Includes:	Q2	19A116201P3	Silicon, NPN.	A10	4EG27A10	Transmitter Oscillator.
Tuning slug.	-		RESISTORS	thru Al2	12021.120	
Coil.			Composition: 6.8K ohms ±5/r, 1/8 w.	1 112		
	R5	3R151P682J				NOTE: When reordering Al3-Al5, give GE Part Number and exact crystal frequency.
RESISTORS	R6	3R151P182J	Composition: 1.8K ohms ±5%, 1/8 w.			
Composition: 180 ohms ±5%, 1/8 w.	R7*	3R151P751J	Composition: 750 ohms ±5/x, 1/8 w.		1	Crystal Freq. (132-150.8 MHz) = $\frac{\text{Fo} -20}{8}$
In REV A:			Earlier than REV A:			
Composition: 220 ohms ±5/r, 1/8 w.		3R151P102J	Composition: 1K ohms ±5%, 1/8 w.			Crystal Freq. (150.8-174 MHz) = $\frac{\text{Fo} -20}{9}$
Earlier than REV A:	R8	3R151P154J	Composition: 150K ohms ±5%, 1/8 w.		1	9
Composition: 390 ohms ±5%, 1/8 w.	R9	3R151P122J	Composition: 1.2K ohms ±5/r, 1/8 w.	A13	4EG28A15	Receiver Oscillator. (132-150.8 MHz).
Composition: 68K ohms ±5%, 1/8 w.	1			thru Al5	4EG28A11	Receiver Oscillator, (150.8-174 MHz).
In REV B and earlier:	F701	19A127884G1	Fuse Kit.		1	
Composition: 91K ohms ±5%, 1/8 w.	1				1	
,					1	
	1	1			1	
1	1	1	1	i i	1	i

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	
٦						Γ
-			JACKS AND RECEPTACLES	15	19A116719P1	1
١	J11*	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	16	19B216862P2	١
-1	thru J14*			17	19A127779G8	1
١		ļ	Earlier than REV A:	18	19B216875Pl	1
١		19A116366P1	Contact, electrical: sim to Cambion 3232-1.	19	19C320352P1	E
-	1			20	19C320383P2	1
to			FRONT COVER ASSEMBLY 19C317416G2 STD 19C317416G6 H1 PWR	21	19A129652P1	3
- 1	1			22	19A129649P1	Į,
ı	.			23	N70P703C6	s
١	LS1	19A116090P1	Permanent magnet: 2.00 inch, 8 ohms ±10% voice coil imp, 450 Hz ±112 Hz resonant; freq range	24	19C317050P1	ŀ
١	. ]		400 to 3000 Hz.	25	19A129390P1	I
١	. 1			26	19A130426G2	١,
١	P1	19A115834P4	Contact, electrical: sim to AMP 2-332070-9.	27	19A129723P1	ŀ
- 1	land	1	,	<b>1</b> i	1	

- - - - - - - - MISCELLANEOUS - - - - - - -

Rear Cover Assembly. Clip type. (See RC2605, items 58, 60).

Antenna Assembly. (See RC2605, items 19-23).

Battery, rechargeable. Nickel Cadmium.

Machine screw, hex head: No. 2-56 x 3/16.

Screw, phillips head: No. 2-56 x 1/8.

Knob, includes items 7, 66. (SQUELCH, ON-OFF-VOLUME).

Case assembly. (Includes items 14, 15, 18, 27, 33-39, 48, 49).

Antenna assembly. (Includes items 19-23).

Nameplate. (GE monogram - standard).

Nameplate. (GE monogram - Hi-Power).

Contact. (Part of J702 and J703).

Alignment tool. Fork tip.

Alignment tool. Allen tip.

Diaphragm: No. 2 inches dia.

Set screw: No. 3-48 x 3/16.

Nut: No. 1/4-32.

Grille, (Standard).

Grille, (Hi-Power).

Washer: teflon.

Fuse Kit.

19B216897G4

19B219953G3

19D413522G1

19A127884G1

4038381P4

19B219079G1

19A134425P1

19C317394P4

N681P5002C6

19a127319P1

N70BP703C6

19B232784G1

198219953G3

190413531P2

198226502G2

NP270290P2

NP270290P3

19B216858P1

19D413542G12

Rear Cover Assembly. (See RC2605, items 58, 59).

ı	<b>42</b> (7			01502	<b>42</b>	
1			l			
١		JACKS AND RECEPTACLES	١	15	19A116719P1	Insert, screw thread: No. 2-56.
ı	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	ı	16	19B216862P2	Contact. (Part of J702).
ı		,	l	17	19A127779G8	Antenna tube.
		Earlier than REV A:	1	18	19B216875P1	Support.
	19A116366P1	Contact, electrical: sim to Cambion 3232-1.	ı	19	19C320352P1	Bushing (Part of item 9).
			l	20	19C320383P2	Antenna rod. (Part of item 9).
		FRONT COVER ASSEMBLY 19C317416G2 STD 19C317416G6 H1 PWR		21	19A129652P1	Nut, knurled: thd size 7/16-40. (Part of item 9).
			ı	22	19A129649P1	Antenna Cap. (Part of item 9).
		LOUDSPEAKERS	ı	23	N70P703C6	Set screw: No. 3-48 x 3/16. (Part of item 9)
i	19A116090P1	Permanent magnet: 2.00 inch, 8 ohms ±10% voice coil imp, 450 Hz ±112 Hz resonant; freq range	١	24	19C317050P1	Protective Cover.
		400 to 3000 Hz.	1	25	19A129390P1	Disc.
			ı	26	19A130426G2	Knob. (Includes items 63, 64).
	19A115834P4	Contact, electrical: sim to AMP 2-332070-9,	1	27	19A129723P1	Rivet.
		,	1	28	19B219540P1	Catch.
			ı	29	19B216520P4	Washer, nylon: 1/4 inch.
		HI/LOW SPLIT MODIFICATION KIT 19A127838Gl 150.8-174 MHz		30	19A127319P2	Nut: No. 1/4-28.
		19A127838G2 132-150.8 MHz	١	31	19B216926P8	Decorative cap. (TYPE 99).
			1	32	19C320721P1	Seal. (used with TYPE 99 Switch).
	19A116114P2047	Ceramic: 33 pf ±5%, 100 VDCW; temp coef -80 PPM.	ı	33	N55P1006	Machine screw: No. 0-80 x 3/8, (Part of S701)
	19A116114P2051	Ceramic: 43 pf ±5%, 100 VDCW; temp coef -80 PPM.	ı	34	19C328416G1	Button assembly. (Part of S701).
			1	35	19C328407P1	Collar. (Part of S701).
		MULTI-FREQUENCY MODIFICATION KIT 19A129762G1	1	36	19A137621P1	Plate. (Part of S701).
				37	19A137620P1	Spring. (Part of S701).
				38	N207P1C6	Nut, hex: No. 10-32. (Part of S701).

19B209643P2

19B216864P1

19B216863P1

N330P605F22

N330P602F22

19A127762Pl

19B216891G1

19D413467Pl

19A115794P3

19B216847P1

19C311491P3

19B219510P1

19A116270Pl

19C317394P6

19B216897G3

19B216897G4

Switch. (Part of S701).

Insulator. (Part of \$702).

Spring contact. (Part of S702).

Retaining ring. (Part of S702).

Contact (Part of S702).

Gasket (Part of S702).

Spring (Part of S702).

Contact. (Part of S702).

Eyelet, brass: 1/16 x 5/32.

Fastener (Part of J704).

Spring assembly. (Part of J704).

Cap screw: 2-56 x 1/4. (Part of S702).

Eyelet, brass: 1/16 x 1/16. (Not Used).

Flat head screw: brass, 2-56 x 5/16. (Part of

n. (Used with Regulator, Oscillator Compensate i Compressor Circuits).

Insulator. (Located between System & Receiver Boards).

Lockwasher, internal tooth: No. 2. (Not Used).

Tape, pressure sensitive. (Specify length).

Rear Cover Assembly (without clip).

Rear Cover Assembly (with clip).

Insulator, pressure sensitive. (Not Used).

SYMBO	OL GE PART NO.	DESCRIPTION
63	N70BP703C6	Set screw: No. 3-48 x 3/16.
64	19A130517P1	Insert, threaded: No. 3-48.
65	4037064P18	Washer, non metallic.
66	19A137254P1	Insert, tap: No. 3-48.
67	19A130993P1	Gasket.
68	N513P604C	Grooved pin. (Not Used).
69	19A127802P1	Rivet, shield.
70	19A116773P805	Tap screw, Phillips POZIDRIV : No. 4-24 x 5/16.
71	N170P9004P2	Cap screw: No. 4-40 x 1/4.
72	FEB 757	Switch assembly: Push to talk. (Includes items 33-39).
73	19A130586P1	Insulator.
74	19B232109P1	Button plug.
75	4033198P18	Metallic eyelet.

GI VIEW "A"	**************************************	9B  "B"  "A"  14 15 16 51 6 51 75 51	20 74 26 19 25 63 17 18 29 17 17 17 17 18 15 16 16 16 16 16 16 16 16 16 16 16 16 16	26 28 27 17  31 32 VIEW "C"  39 38 33  VIEW "D" 34 35 72  36 40 41 42 47 43 44 45 VIEW "E"
VIEW "B"	54	VIEW "G"	VIEW "F"	RC-2605J

\*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

## **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Case Assembly 19D417103G1
Incorporated into initial shipment.

REV. B - Case Assembly 19D417103G1

To make compatible with more options. Deleted K1.

REV. C - To improve design. Added insulator.

REV. D - To improve design. Changed screws in PTT switch S701.

REV. A - System Board 19D417100G1

To make compatible with more options.
Added Kl and increased the size of runs
on printed wire board.

REV. B - To improve PTT relay pick-up performance at low voltage. Changed Kl and Rl.

REV. C - To increase modulation level and improve frequency response. Changed C3, C5, R2, and R5. Deleted R6.

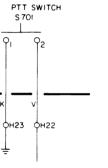
REV. D - To improve frequency response. Changed C3 and C5.

REV. E - To incorporate a new 5.4 V Regulator module. Changed A2 and added C21.

REV. E - <u>Case Assembly 19D417103G1</u>

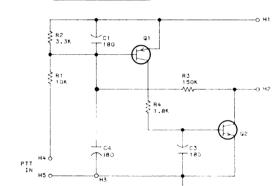
To improve reliability changed S701 and added A705. Also, changed knobs.

Schematic Diagram was:

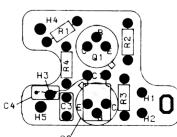


REV. F - To make new PTT Switch compatible with GE-STAR. Changed A705.

Schematic Diagram was:



Outline Diagram was:



REV. A - PTT Circuit 19B232586G1 To improve RF filtering. Added C4.

REV. A - PTT Circuit 19B232586G2 To improve performance deleted C1 and changed R7.

REV. B - To improve RF filtering. Added C5.

REV. C - To make compatible with GE-STAR changed circuit or printed wire board and added C2.

LBI4702

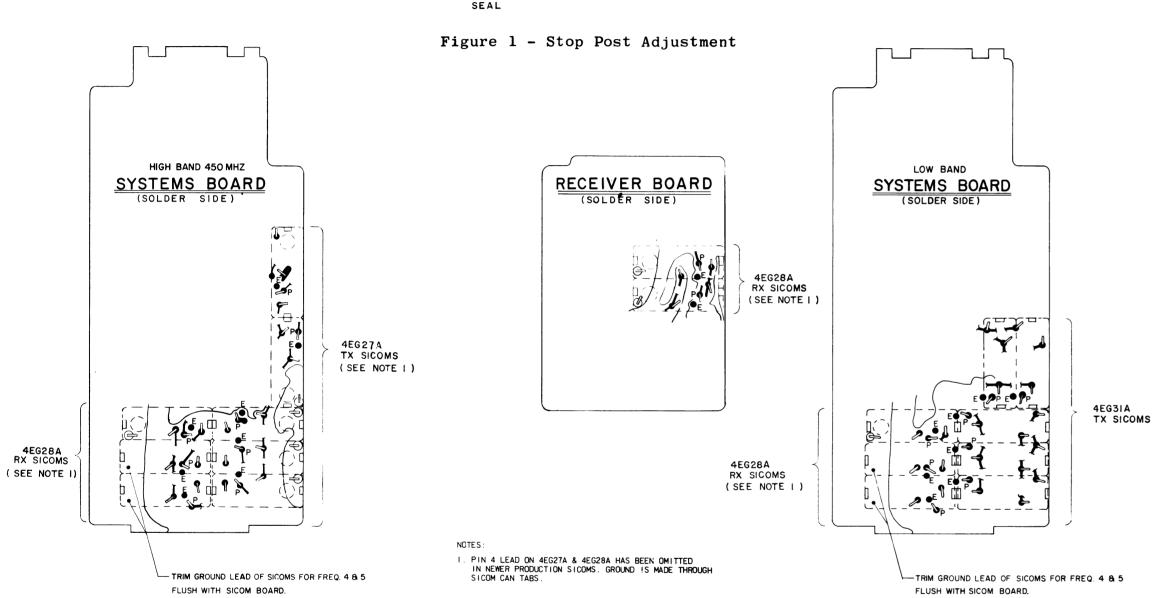
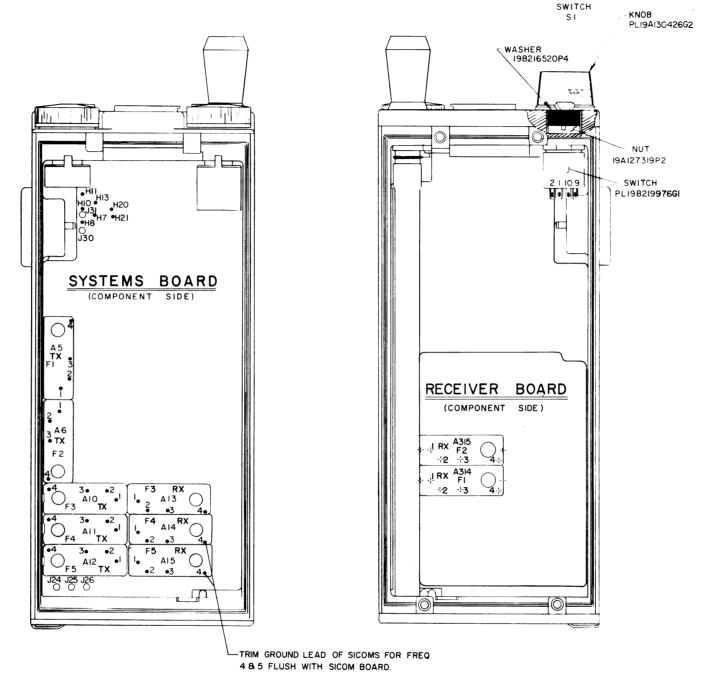


Figure 2 - Oscillator Module and Diode Installation

## **MULTI-FREQUENCY MODIFICATIONS**

(19D417138, Sh. 2, Rev. 3)



MULTI-FREQUENCY

Figure 3 - Oscillator Mounting Positions & Sl Connection Points

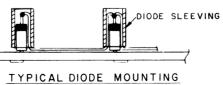


Figure 4 - Typical Diode Mounting

#### (19D417138, Sh. 1, Rev. 5 & Sh. 2, Rev. 3)

The multi-frequency modifications include instructions for adjusting the stop post on multi-frequency switch Sl, for adding oscillator modules, for repeating frequencies, and repeating oscilla-

MULTI-FREQUENCY MODIFICATIONS

### 1- STOP POST ADJUSTMENT

CAUTION ....

Due to the small size of the stop posts, be very careful when making adjustments to avoid losing

- 1. Remove the multi-frequency switch as directed in the
- 2. Turn the shaft fully counterclockwise as viewed from
- Unscrew the panel seal to gain access to the stop post (see Figure 1).
- 4. Install the stop post in the appropriate hole as shown in the following chart.

NO. OF FREQS	MOVE ADJUSTABLE STOP TO
2	Н2
3	н3
4	H <b>4</b>
5	Н5

- 5. Replace the panel seal with the side marked "Bottom" against
- 6. Re-install the Multifrequency Switch.

## 2- ADDING OSCILLATOR MODULES

1. After completing the stop post adjustment, connect the leads from multi-frequency switch Sl as shown in the following chart (see Figure 3 for connection points). Tape back all unused leads.

FROM	то	WIRE COLOR	S1 POSITION
S1-C1	Hll (solder)	SFT-BL	
S1-1	J31	SFT-W-BK	1
S1-2	J30	SFT-W-O	2
S1-3	J24	BR	3
S1-4	J25	R	4
S1-5	J26	0	5

2. Place the oscillator module(s) in the proper holes (see the adjacent pads (see Figure 2).

- 3. Bend the leads of the oscillator module as shown in Figure 2 (or appropriate Outline Diagram) and solder to the adjacent nade
- 4. For two or more transmitter frequencies and one receiver frequency, remove the jumper from H7 to H10 and add a sleeved jumper (#26 AWG) from H7 to H13 on the Systems
- For two or more receiver frequencies and one transmitter frequency, remove the jumper from H8 to H10 and add a sleeved jumper (#26 AWG) from H20 and H21 on the Systems

### 3- REPEATING FREQUENCIES

For repeating both transmitter and receiver frequencies without adding additional oscillator modules, add a sleeved jumper #26 AWG) between the frequencies to be repeated. For example, if transmitter and receiver channels 1 and 5 are to be repeated, add the jumper from S1-1 to S1-5.

### 4- REPEATING OSCILLATOR MODULES

To repeat frequencies for the transmitter only or the receiver only, diodes can be used in place of oscillator modules.

- 1. Set the stop on S1 and install the oscillator modules whose frequencies are not to be repeated as directed in Section I
- Install the oscillator(s) whose frequencies are to be repeated as directed above except solder the Number 2 pin to the "E" pad instead of the "P" pad (see Figure 2).
- For every channel that a frequency is being repeated, assemble a diode (5494922Pl) in the space normally intended for the oscillator module by putting the annode lead in the Number 2 hole, bending it over and soldering to the "P" pad. The cathode lead will be terminated
- 4. For each different frequency that is repeated, an additional diode (5494922P1) is to be assembled in respective channel closest to the oscillator module being repeated. Assemble the diode in the Number 1 hole, annode lead down and sleeved, and connect to the associated "E" pad. Then run the jumper from this pad to the "P" pad of related oscil-

The cathode end of the diodes should be connected together using mid air connections. Make the connection and run the wire down the side of the diode along the component side of the board to the next diode, and so on until all the diode's cathodes are connected together. Route these wires to give the shortest connections. Now connect a lead to the cathode of the diode that is closest to the repeated oscillator module and run this lead down the side of the diode and through any empty hole or slot to the solder side of the board, and connect the lead to the "E" pad of the oscillator module. Next sleeve

Example: Channel 3 and 4 to be same as Channel 1. Channel 5 to be same as Channel 2.

(This example applies TX Frequencies only).

- 1. Assemble the oscillator module in Channels 1 and 2 as normal except connect the Number 2 lead to the "E" pad instead of "P" pad.
- Assemble (1) diode in the Number 2 hole, anode lead down, in each of Channels 1, 3, 4 & 5 and solder to "P" pads.
- Since two frequencies are being repeated, two additional diodes will be required, one in the Number 1 hole of Channel 3 and the other in the Number 1 hole of Channel 5. Sleeve, bend, and solder leads to the "E" pad. Connect jumper between the "E" pad of the Number 3 Channel and "P" pad of oscillator module Number 1. Connect a jumper between the "E" pad of Number 5 Channel and "P" pad of oscillator module Number 2.
- 4. Connect the top lead (cathode) of diodes (3) in Channel 3 and 4 to each other by soldering jumper wire to leads, dressing the wire down the side of the diodes and along the board. Connect a jumper from the top of diode in the Number 1 hole of Channel 3 to the "E" pad of oscillator module Number 1. Run the wire down through the board using any available hole or slot to the solder side. Connect the jumper from the diode in Channel Number 5 to oscillator module Number 2 in the same manner.

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